## Silicon Controlled Rectifiers Reverse Blocking Thyristors

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supplies.

### Features

- Glass Passivated Junctions with Center Gate Geometry for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Blocking Voltage to 800 V
- These are Pb-Free Devices

## **MAXIMUM RATINGS**<sup>†</sup> (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	V <sub>DRM,</sub> V <sub>RRM</sub>	50 100 400 800	V
On-State RMS Current (180° Conduction Angles; T <sub>C</sub> = 90°C)	I <sub>T(RMS)</sub>	12	A
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave, 60 Hz, T <sub>J</sub> = 90°C)	I <sub>TSM</sub>	100	A
Circuit Fusing (t = 8.3 ms)	l <sup>2</sup> t	40	A <sup>2</sup> s
Forward Peak Gate Power (Pulse Width $\leq$ 1.0 $\mu s,~T_C$ = 90°C)	P <sub>GM</sub>	20	W
Forward Average Gate Power (t = 8.3 ms, $T_C = 90^{\circ}C$ )	P <sub>G(AV)</sub>	0.5	W
Forward Peak Gate Current (Pulse Width $\leq$ 1.0 $\mu$ s, T <sub>C</sub> = 90°C)	I <sub>GM</sub>	2.0	A
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C

MAXIMUM RATINGS<sup>†</sup> (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.0	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	ΤL	260	°C

†Indicates JEDEC Registered Data

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

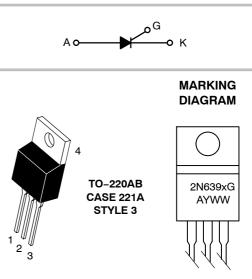
 V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

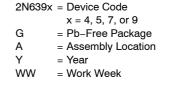


## **ON Semiconductor®**

http://onsemi.com

## SCRs 12 AMPERES RMS 50 thru 800 VOLTS





PIN ASSIGNMENT		
1	Cathode	
2	Anode	
3	Gate	
4	Anode	

### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
DFF CHARACTERISTICS	•			•	
†Peak Repetitive Forward or Reverse Blocking Current $(V_{AK} = Rated V_{DRM} \text{ or } V_{RRM}, Gate Open)$ $T_J = 25^{\circ}C$	I <sub>DRM</sub> , I <sub>RRM</sub>			10	۸
$      (V_{AK} = Rated V_{DRM} \text{ or } V_{RRM}, \text{ Gate Open} )                                   $		_	_	2.0	μA mA
ON CHARACTERISTICS	-				
†Peak Forward On-State Voltage (Note 2) (I <sub>TM</sub> = 24 A Peak)		-	1.7	2.2	V
†Gate Trigger Current (Continuous dc) (V <sub>D</sub> = 12 Vdc, R <sub>L</sub> = 100 Ohms)		-	5.0	30	mA
†Gate Trigger Voltage (Continuous dc) (V <sub>D</sub> = 12 Vdc, R <sub>L</sub> = 100 Ohms)		-	0.7	1.5	V
Gate Non-Trigger Voltage (V <sub>D</sub> = 12 Vdc, R <sub>L</sub> = 100 Ohms, T <sub>J</sub> = 125°C)		0.2	-	-	V
†Holding Current (V <sub>D</sub> = 12 Vdc, Initiating Current = 200 mA, Gate Open)		-	6.0	50	mA
Turn-On Time ( $I_{TM}$ = 12 A, $I_{GT}$ = 40 mAdc, $V_D$ = Rated $V_{DRM}$ )		-	1.0	2.0	μs
Turn-Off Time ( $V_D$ = Rated $V_{DRM}$ ) ( $I_{TM}$ = 12 A, $I_R$ = 12 A)	tq	-	15	-	μs
$(I_{TM} = 12 \text{ A}, T_{J} = 125^{\circ}\text{C})$		-	35	-	
DYNAMIC CHARACTERISTICS					
Critical Rate-of-Rise of Off-State Voltage Exponential	dv/dt	-	50	_	V/us

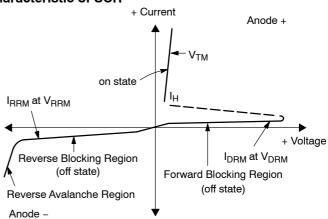
 $(V_D = \text{Rated } V_{DRM}, T_J = 125^{\circ}\text{C})$ 

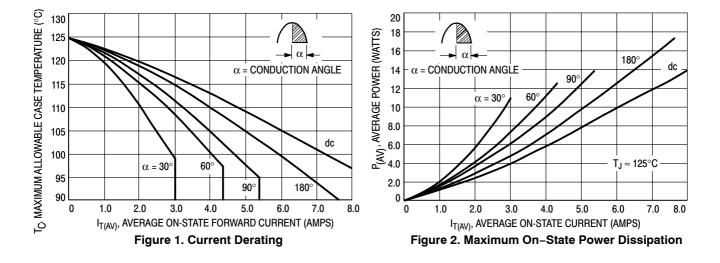
†Indicates JEDEC Registered Data

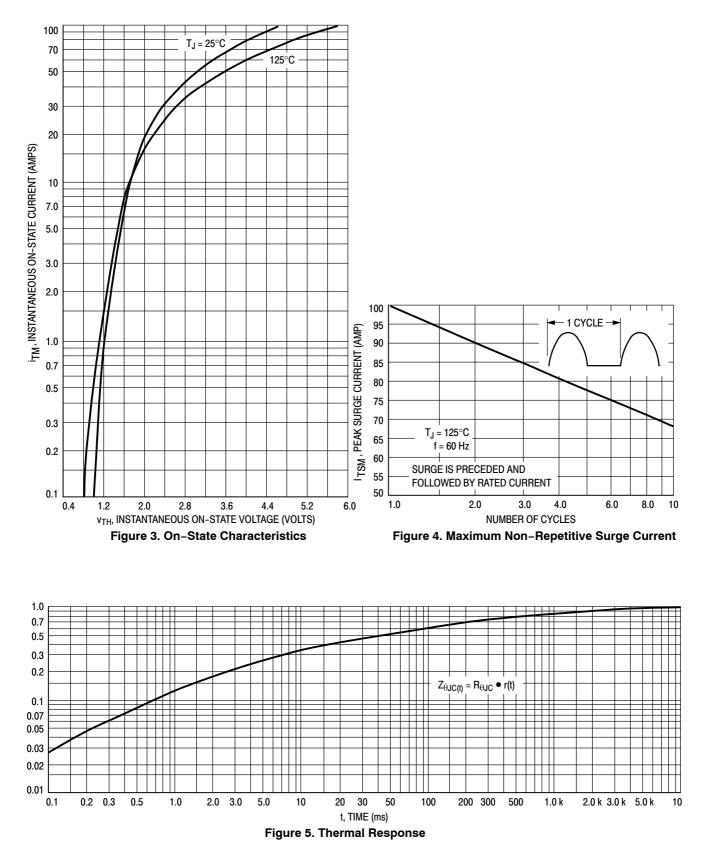
2. Pulse Test: Pulse Width  $\leq$  300  $\mu sec,$  Duty Cycle  $\leq$  2%.

## Voltage Current Characteristic of SCR

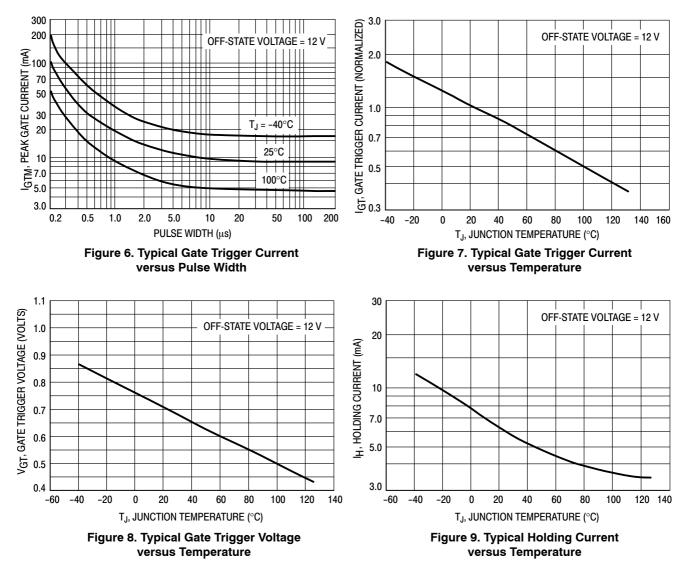
Symbol	Parameter
V <sub>DRM</sub>	Peak Repetitive Off State Forward Voltage
I <sub>DRM</sub>	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Off State Reverse Voltage
I <sub>RRM</sub>	Peak Reverse Blocking Current
V <sub>TM</sub>	Peak On State Voltage
I <sub>H</sub>	Holding Current







### **TYPICAL CHARACTERISTICS**



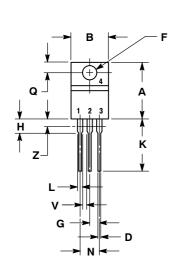
#### **ORDERING INFORMATION**

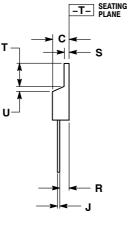
Device	Package	Shipping**
2N6394G		500 Units / Bulk
2N6394TG		50 Units / Rail
2N6395G		500 Units / Bulk
2N6397G	TO-220AB (Pb-Free)	500 Units / Bulk
2N6397TG	()	50 Units / Rail
2N6399G		500 Units / Bulk
2N6399TG		50 Units / Rail

\*\*For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

**TO-220AB** CASE 221A-07 **ISSUE AA** 





NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14 5M 1982

 CONTROLLING DIMENSION: INCH.
DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Η	0.110	0.155	2.80	3.93
ſ	0.014	0.022	0.36	0.55
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
۷	0.045		1.15	
Ζ		0.080		2.04

STYLE 3: PIN 1. CATHODE

2. ANODE

3. GATE

ANODE 4

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Authorized Distributor

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